

SUPER LOW OPERATING CURRENT AND LOW OFFSET VOLTAGE TINY SINGLE C-MOS OPERATIONAL AMPLIFIER

■ GENERAL DESCRIPTION

The NJU7006 is a super low operating current and low offset voltage tiny single C-MOS operational amplifier.

The input offset voltage is lower than 2mV (max) and the input bias current is as low as less than 1pA (typ),consequently the very small signal around the ground level can be amplified.

The operating current is $3\mu A$ (typ),and the output stage permits output signals to swing between both of the supply rails.

Furthermore, the NJU7006 is packaged with very small MTP-5,therefore it can be especially applied to battery operated portable items.

■ PACKAGE OUTLINE



NJU7006F

■ FEATURES

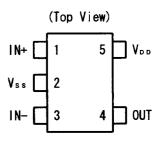
 $\begin{array}{lll} \bullet & \text{Super Low Operating Current} & (I_{DD} = 3.0 \mu \text{A typ.} \,) \\ \bullet & \text{Single Power Supply} & (V_{DD} = 1.8 \sim 3.6 \text{V} \,) \\ \bullet & \text{Low Offset Voltage} & (V_{IO} = 2 \text{mV max.} @ 3.0 \text{V} \,) \\ \bullet & \text{Wide Output Swing Range} & (V_{OM} = 2.9 \text{V min.} @ 3.0 \text{V} \,) \\ \bullet & \text{Low Bias Current} & (I_{IB} = 1 \text{pA typ.} \,) \end{array}$

• Compensation Capacitor Incorporated

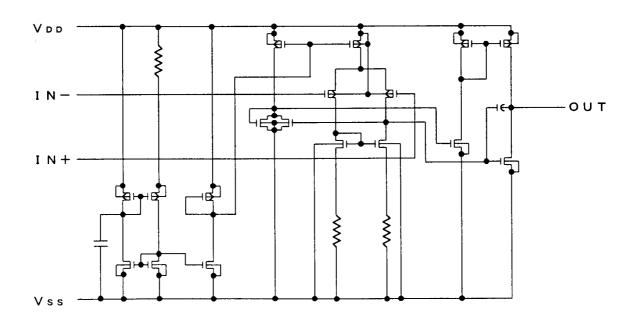
Package Outline
 MTP5

C-MOS Technology

■ PIN CONFIGURATION



■ EQUIVALENT CIRCUIT



■ ABSOLUTE MAXIMUM RATINGS

(Ta=25°C)

PARAMETER	SYMBOL	RATINGS	UNIT
Supply Voltage	V _{IN}	7	V
Differential Input Voltage	V_{ID}	±7 (note1)	V
Common Mode Input Voltage	V _{IC}	-0.3~7	V
Power Dissipation	P_D	200	mW
Operating Temperature Range	T _{opr}	-40~+85	°C
Storage Temperature Range	T _{stg}	-55~+125	°C

⁽ note1) If the supply voltage (V_{DD}) is less than 7V, the input voltage must not over the V_{DD} level though 7V is limit specified.

■ ELECTRICAL CHARACTERISTICS

 $(Ta=25^{\circ}C,V_{DD}=3.0V,R_{L}=\infty)$

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Input Offset Voltage	V_{IO}	$V_{IN}=1/2V_{DD}$	-	-	2	mV
Input Offset Current	I _{IO}		-	1	-	pА
Input Bias Current	I_{IB}		-	1	-	pА
Input Impedance	R _{IN}		-	1	-	ΤΩ
Large Signal Voltage Gain	A_{VD}		60	70	-	dB
Input Common Mode Voltage Range	V_{ICM}		0~2.5	-	-	V
Maximum Output Swing Voltage	V _{OM1}	$R_L=10M\Omega$	V _{DD} -0.1	-	-	V
	V _{OM2}	$R_L=10M\Omega$	-	-	V _{SS} +0.1	V
Common Mode Rejection Ratio	CMR	$V_{IN}=1/2V_{DD}$	55	65	-	dB
Supply Voltage Rejection Ratio	SVR	V _{DD} =3.0~3.6V	60	70	-	dB
Operating Current	I _{DD}		-	3.0	4.5	μA
Slew Rate	SR	C _L =10pF	0.02	0.04	-	V/µs
Unity Gain Bandwidth	Ft	A _√ =40dB,C _L =10pF	-	95	-	kHz

⁽ note3) The source current is less than 0.29 μA (at V_{OM}/R_L =2.9V/10M Ω).

[CAUTION]

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⁽ note2) Decoupling capacitor should be connected between V_{DD} and V_{SS} $\,$ for the stable operation.

⁽ note4) The load capacitance ($\mbox{C}_{\mbox{\scriptsize L}}$) is less than 200pF.